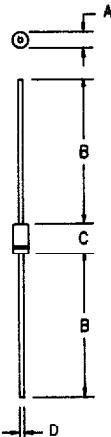


1 Amp Schottky Rectifier

MSG108, 109, 110

C



Dim.	Inches		Millimeter		
	Minimum	Maximum	Minimum	Maximum	Notes
A	.081	.107	2.057	2.718	Dia.
B	1.10	---	27.94	---	
C	.160	.205	4.064	5.207	
D	.028	.034	.711	.864	Dia.

GLASS HERMETIC DO41

Microsemi Catalog Number	Working Peak Reverse Voltage	Repetitive Peak Reverse Voltage	• Schottky Barrier Rectifier • Guard Ring Protection • 175°C Junction Temperature • V _{RRM} 80 to 100 Volts
MSG108	80V	80V	
MSG109	90V	90V	
MSG110	100V	100V	

Electrical Characteristics	
Average forward current	I _{F(AV)} 1.0 Amps
Average forward current	I _{F(AV)} 1.0 Amps
Maximum surge current	I _{FSM} 75 Amps
Max peak forward voltage	V _{FM} .53 Volts
Max peak forward voltage	V _{FM} .81 Volts
Max peak reverse current	I _{RM} 100 μ A
Typical junction capacitance	C _J 45pF
	T _A = 135°C Square wave, R _{θJL} = 50°C/W, L = 0"
	T _A = 120°C Square wave, R _{θJL} = 68°C/W, L = 3/8"
	8.3ms, half sine, T _J = 175°C
	I _{FM} = 0.1A; T _J = 25°C*
	I _{FM} = 1.0A; T _J = 25°C*
	V _{RRM} ; T _J = 25°C
	V _R = 5.0V, T _J = 25°C

*Pulse test: Pulse width 300 μ sec, Duty cycle 2%

Thermal and Mechanical Characteristics			
Storage temperature range	T _{SIG}	-40°C to 175°C	
Operating junction temp range	T _J	-40°C to 175°C	
Maximum thermal resistance	L = 3/8"	R _{θJL}	68°C/W
	L = 0	R _{θJL}	50°C/W
			Junction to Lead
Weight			.011 ounces (0.34 grams) typical

MSG108, 109, 110

Figure 1
Typical Forward Characteristics

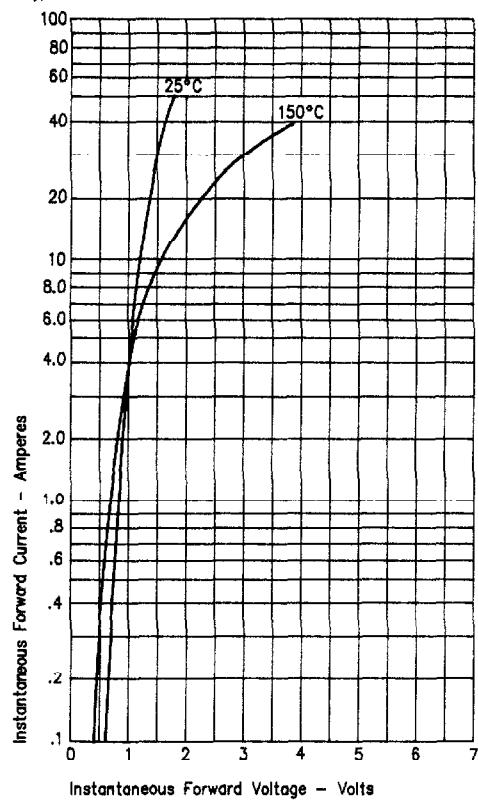


Figure 3
Typical Junction Capacitance

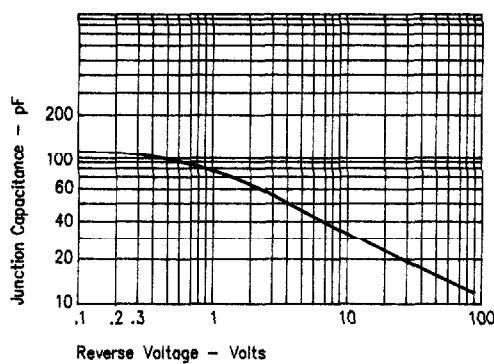


Figure 2
Typical Reverse Characteristics

